TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSVII)

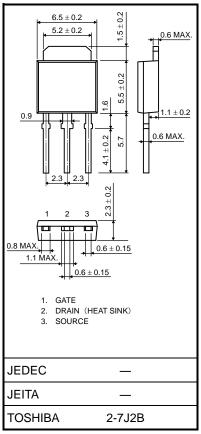
TK2Q60D

Switching Regulator Applications

- Low drain-source ON-resistance: R_{DS} (ON) = 3.2 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 1.0 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 600 \ V)$
- Enhancement mode: $V_{th} = 2.4$ to 4.4 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Characteristics			Symbol	Rating	Unit			
Drain-source voltage			V _{DSS}	600	V			
Gate-source voltage			V _{GSS}	±30	V			
Drain current	DC	(Note 1)	ID	2	٨			
	Pulse	(Note 1)	IDP	8	A			
Drain power dissipation (Tc = 25°C)			PD	60	W			
Single pulse avalanche energy (Note 2)			Eas	101	mJ			
Avalanche current			I _{AR}	2	А			
Repetitive avalanche energy (Note 3)			Ear	6.0	mJ			
Channel temperature			T _{ch}	150	°C			
Storage temperature range			T _{stg}	-55 to 150	°C			

Absolute Maximum Ratings (Ta = 25°C)



Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

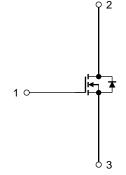
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.08	°C/W
Thermal resistance, channel to ambient	Rth (ch-a)	125	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: VDD = 90 V, Tch = 25°C(initial), L = 44.1 mH, RG = 25 Ω , IAR = 2 A



This transistor is an electrostatic-sensitive device. Handle with care.



Start of commercial production 2009-03

Unit: mm

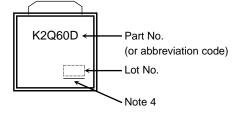
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	IGSS	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_	_	±1	μA
Drain cut-off current		IDSS	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	10	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	600	600 — —		V
Gate threshold ve	oltage	V _{th}	$V_{DS} = 10 V, I_D = 1 mA$	2.4	_	4.4	V
Drain-source ON	resistance	R _{DS} (ON)	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ A}$	_	3.2	4.3	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 V, I_{D} = 1 A$	0.3	1.0	_	S
Input capacitance		Ciss		_	280	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS}=25~V,~V_{GS}=0~V,~f=1~MHz$	_	1.5	_	
Output capacitance		C _{oss}		_	30	_	
Switching time	Rise time	tr	$I_D = 1 \text{ A } V_{OUT}$ VGS	_	15	_	
	Turn-on time	t _{on}	$\begin{bmatrix} 0 \ \lor & \checkmark & \lor & \lor \\ 0 \ \lor & \checkmark & \lor & \lor \\ 50 \ \Omega \end{bmatrix} \notin R_{L} = 200 \ \Omega$	_	35	_	
	Fall time	tf	 		7	_	ns
	Turn-off time	t _{off}	Duty \leq 1%, t _w = 10 μ s	_	55	_	
Total gate charge		Qg		_	7	_	
Gate-source charge		Qgs	$V_{DD}\approx 400~V,~V_{GS}=10~V,~I_{D}=2~A$	_	4	_	nC
Gate-drain charge		Qgd		_	3	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	2	A
Pulse drain reverse current (Note 1)	IDRP	—	-	_	8	А
Forward voltage (diode)	VDSF	$I_{DR} = 2 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	-	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR}=2\text{ A},V_{GS}=0V,$	-	550	_	ns
Reverse recovery charge	Qrr	dI _{DR} /dt = 100 A/μs		2.2	—	μC

Marking



Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

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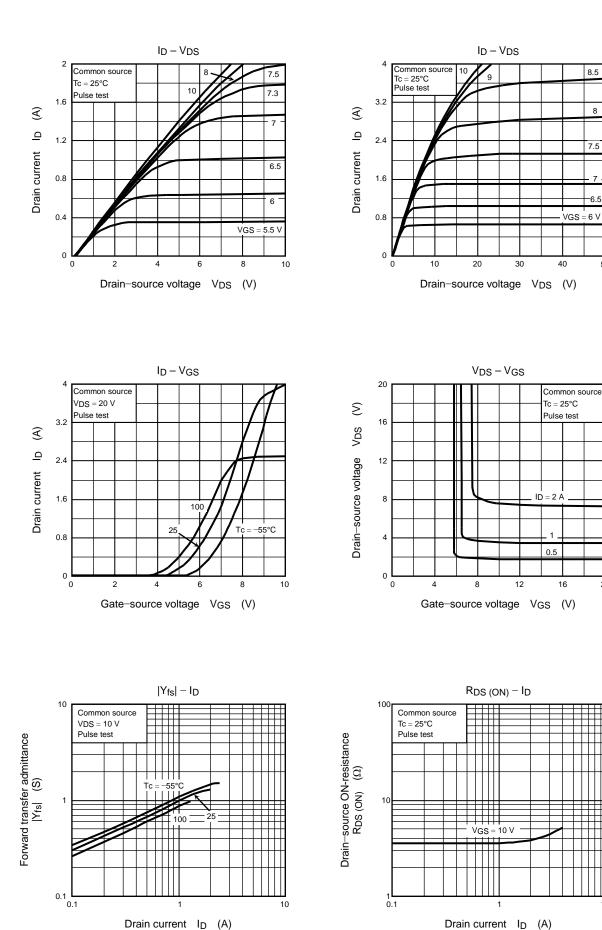
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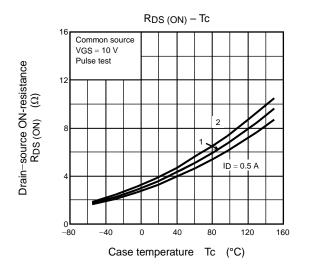
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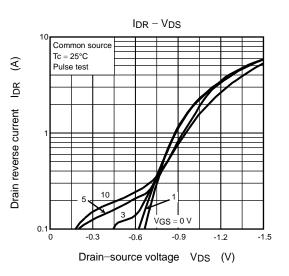
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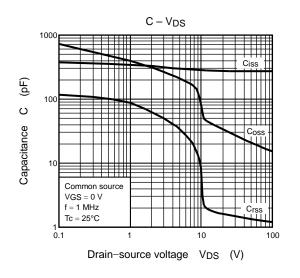


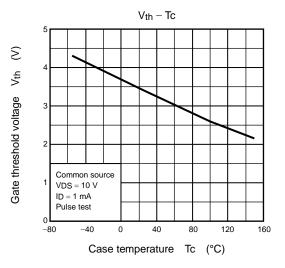
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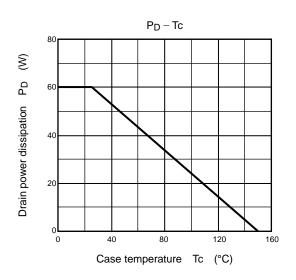
Drain current ID (A)

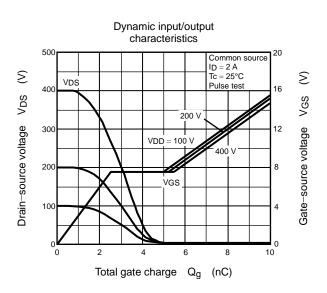


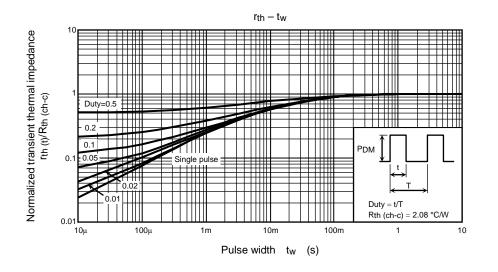


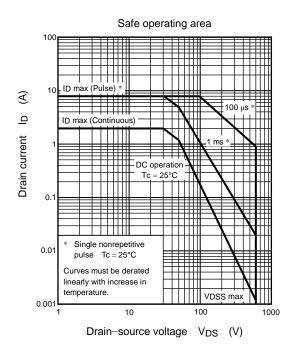


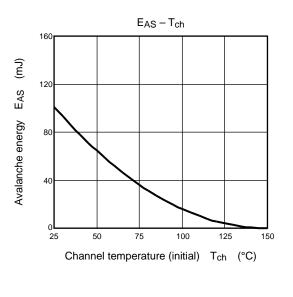


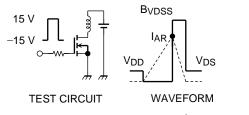












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